

## Rail-to-rail high output current dual operational amplifier

### Features

- Rail-to-rail input and output
- Low noise: 9 nV/  $\sqrt{\text{Hz}}$
- Low distortion
- High output current: 80 mA (able to drive 32  $\Omega$  loads)
- High-speed: 4 MHz, 1 V/ $\mu\text{s}$
- Operating from 2.7 to 12 V
- Low input offset voltage: 900  $\mu\text{V}$  max (TS922A)
- ESD internal protection: 2 kV
- Latch-up immunity
- Macromodel included in this specification
- Dual version available in flip-chip package

### Applications

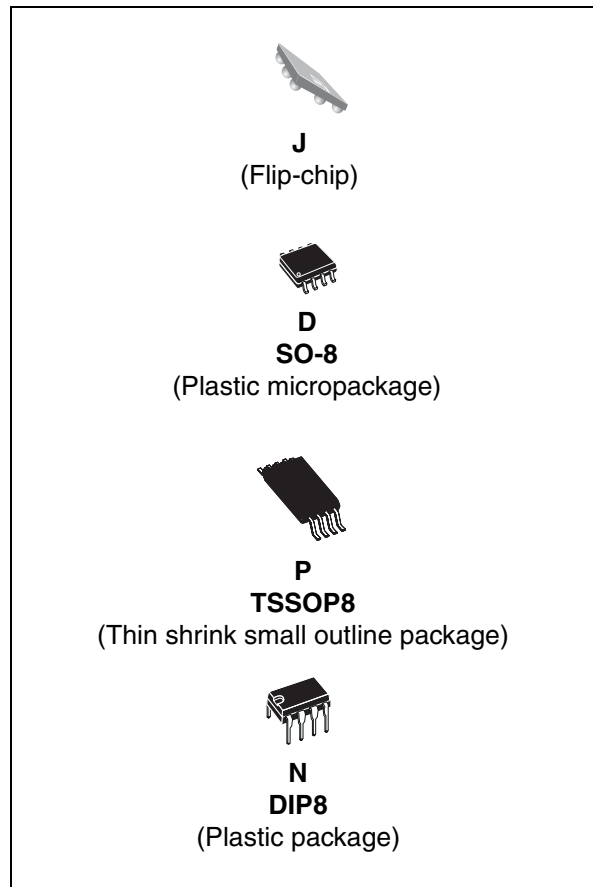
- Headphone amplifiers
- Sound cards, multimedia systems
- Line drivers, actuator drivers
- Servo amplifiers
- Mobile phones and portable equipment
- Instrumentation with low noise as key factor
- Piezoelectric speaker drivers

### Description

The TS922 is a rail-to-rail dual BiCMOS operational amplifier optimized and fully specified for 3 and 5 V operation.

The device's high output current allows low-load impedances to be driven.

Very low noise, low distortion, low offset and a high output current capability make this device an excellent choice for high quality, low voltage or battery operated audio systems.



The device is stable for capacitive loads up to 500 pF.

# 1 Pin diagrams

Figure 1. Pin connections (top view)

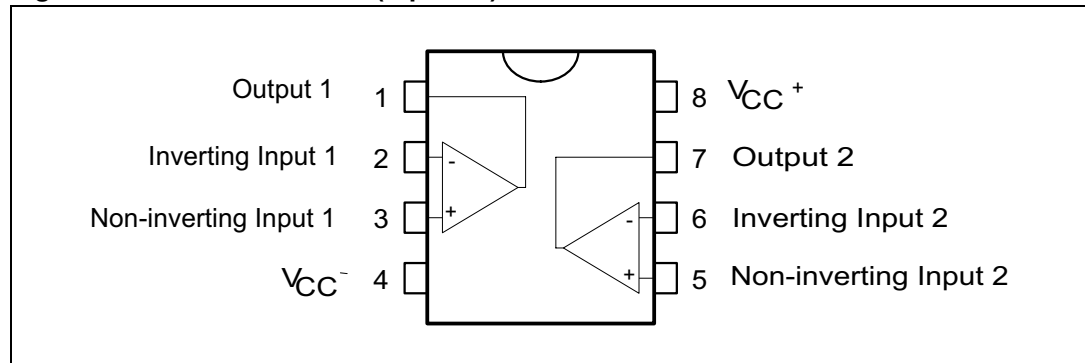
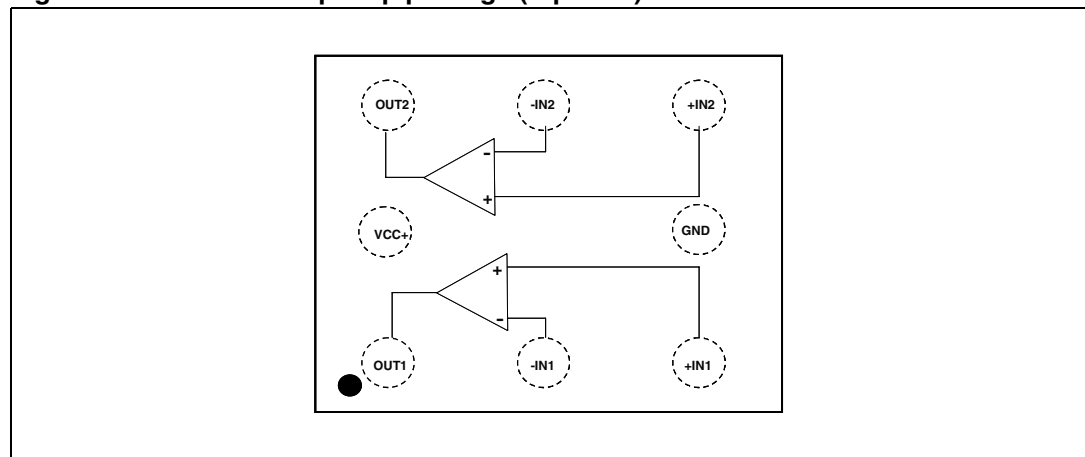


Figure 2. Pinout for flip-chip package (top view)



## 2 Absolute maximum ratings and operating conditions

**Table 1. Absolute maximum ratings (AMR)**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage <sup>(1)</sup>	14	V
$V_{id}$	Differential input voltage <sup>(2)</sup>	$\pm 1$	V
$V_{in}$	Input voltage <sup>(3)</sup>	$V_{CC-} - 0.3$ to $V_{CC+} + 0.3$	V
$T_{stg}$	Storage temperature	-65 to +150	°C
$R_{thja}$	Thermal resistance junction to ambient <sup>(4)</sup>		
	SO-8	125	°C/W
	TSSOP8	120	
	Flip-chip	90	
$R_{thjc}$	Thermal resistance junction to case <sup>(4)</sup>		
	SO-8	40	°C/W
	TSSOP8	37	
$T_j$	Maximum junction temperature	150	°C
ESD	HBM: human body model <sup>(5)</sup>	2000	
	MM: machine model <sup>(6)</sup>	120	V
	CDM: charged device model <sup>(7)</sup>	1500	
	Output short-circuit duration	See note <sup>(8)</sup>	
	Latch-up immunity	200	mA
	Soldering temperature (10 sec), leaded version	250	
	Soldering temperature (10 sec), unleaded version	260	°C

1. All voltage values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal. If  $V_{id} > \pm 1$  V, the maximum input current must not exceed  $\pm 1$  mA. In this case ( $V_{id} > \pm 1$  V), an input series resistor must be added to limit the input current.
3. Do not exceed 14 V.
4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuits on all amplifiers. These values are typical.
5. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5k $\Omega$  resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
6. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor  $< 5 \Omega$ ). This is done for all couples of connected pin combinations while the other pins are floating.
7. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.
8. There is no short-circuit protection inside the device: short-circuits from the output to  $V_{CC}$  can cause excessive heating. The maximum output current is approximately 80 mA, independent of the magnitude of  $V_{CC}$ . Destructive dissipation can result from simultaneous short-circuits on all amplifiers.

**Table 2. Operating conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	2.7 to 12	V
$V_{icm}$	Common mode input voltage range	$V_{CC-} - 0.2$ to $V_{CC+} + 0.2$	V
$T_{oper}$	Operating free air temperature range	-40 to +125	°C

### 3 Electrical characteristics

**Table 3. Electrical characteristics measured at  $V_{CC} = +3\text{ V}$ ,  $V_{DD} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25^\circ\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{io}$	Input offset voltage	TS922 TS922A TS922IJ (flip-chip)			3 0.9 1.5	mV
		$T_{min} \leq T_{amb} \leq T_{max}$ TS922 TS922A TS922IJ (flip-chip)			5 1.8 2.5	
$DV_{io}$	Input offset voltage drift			2		$\mu\text{V}/^\circ\text{C}$
$I_{io}$	Input offset current	$V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		1	30 30	nA
$I_{ib}$	Input bias current	$V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		15	100 100	nA
$V_{OH}$	High level output voltage	$R_L = 10\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	2.90 2.90			V
		$R_L = 600\text{ }\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	2.87 2.87			V
		$R_L = 32\text{ }\Omega$		2.63		V
$V_{OL}$	Low level output voltage	$R_L = 10\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$			50 50	mV
		$R_L = 600\text{ }\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$			100 100	mV
		$R_L = 32\text{ }\Omega$		180		mV
$A_{vd}$	Large signal voltage gain	$R_L = 10\text{ k}\Omega$ , $V_{out} = 2\text{ V}_{p-p}$ $T_{min} \leq T_{amb} \leq T_{max}$	70	200		V/mV
		$R_L = 600\text{ }\Omega$ , $V_{out} = 2\text{ V}_{p-p}$ $T_{min} \leq T_{amb} \leq T_{max}$	15	35		
		$R_L = 32\text{ }\Omega$ , $V_{out} = 2\text{ V}_{p-p}$		16		
$I_{CC}$	Total supply current	No load, $V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		2	3 3.2	mA
GBP	Gain bandwidth product	$R_L = 600\text{ }\Omega$		4		MHz
CMR	Common mode rejection ratio	$T_{min} \leq T_{amb} \leq T_{max}$	60 56	80		dB
SVR	Supply voltage rejection ratio	$V_{CC} = 2.7\text{ to }3.3\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$	60 60	85		dB
$I_o$	Output short-circuit current		50	80		mA
SR	Slew rate		0.7	1.3		V/ $\mu\text{s}$
$\phi_m$	Phase margin at unit gain	$R_L = 600\text{ }\Omega$ , $C_L = 100\text{ pF}$		68		Degrees

**Table 3. Electrical characteristics measured at  $V_{CC} = +3\text{ V}$ ,  $V_{DD} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25^\circ\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified) (continued)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$G_m$	Gain margin	$R_L = 600\ \Omega$ , $C_L = 100\text{ pF}$		12		dB
$e_n$	Equivalent input noise voltage	$f = 1\text{ kHz}$		9		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
THD	Total harmonic distortion	$V_{out} = 2\text{ V}_{p-p}$ , $f = 1\text{ kHz}$ , $A_v = 1$ , $R_L = 600\ \Omega$		0.005		%
$C_s$	Channel separation			120		dB

**Table 4. Electrical characteristics measured at  $V_{CC} = 5\text{ V}$ ,  $V_{DD} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25^\circ\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified)**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_{io}$	Input offset voltage	TS922 TS922A TS922IJ (flip-chip)			3 0.9 1.5	mV
		$T_{min} \leq T_{amb} \leq T_{max}$ TS922 TS922A TS922IJ (flip-chip)			5 1.8 2.5	
$DV_{io}$	Input offset voltage drift			2		$\mu\text{V}/^\circ\text{C}$
$I_{io}$	Input offset current	$V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		1	30 30	nA
$I_{ib}$	Input bias current	$V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		15	100 100	nA
$V_{OH}$	High level output voltage	$R_L = 10\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	4.9 4.9			V
		$R_L = 600\ \Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	4.85 4.85			
		$R_L = 32\ \Omega$		4.4		
$V_{OL}$	Low level output voltage	$R_L = 10\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$			50 50	mV
		$R_L = 600\ \Omega$ $T_{min} \leq T_{amb} \leq T_{max}$			120 120	
		$R_L = 32\ \Omega$		300		
$A_{vd}$	Large signal voltage gain	$R_L = 10\text{ k}\Omega$ $V_{out} = 2\text{ V}_{p-p}$ $T_{min} \leq T_{amb} \leq T_{max}$	70	200		V/mV
		$R_L = 600\ \Omega$ $V_{out} = 2\text{ V}_{p-p}$ $T_{min} \leq T_{amb} \leq T_{max}$	20	35		
		$R_L = 32\ \Omega$ $V_{out} = 2\text{ V}_{p-p}$		16		
$I_{cc}$	Total supply current	No load, $V_{out} = V_{CC}/2$ $T_{min} \leq T_{amb} \leq T_{max}$		2	3 3.2	mA
GBP	Gain bandwidth product	$R_L = 600\ \Omega$		4		MHz
CMR	Common mode rejection ratio	$T_{min} \leq T_{amb} \leq T_{max}$	60 56	80		dB
SVR	Supply voltage rejection ratio	$V_{CC} = 4.5\text{ to }5.5\text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$	60 60	85		dB
$I_o$	Output short-circuit current		50	80		mA
SR	Slew rate		0.7	1.3		V/ $\mu\text{s}$
$\phi_m$	Phase margin at unit gain	$R_L = 600\ \Omega$ $C_L = 100\text{ pF}$		68		Degrees
$G_m$	Gain margin	$R_L = 600\ \Omega$ $C_L = 100\text{ pF}$		12		dB
$e_n$	Equivalent input noise voltage	$f = 1\text{ kHz}$		9		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$

**Table 4. Electrical characteristics measured at  $V_{CC} = 5\text{ V}$ ,  $V_{DD} = 0\text{ V}$ ,  $V_{icm} = V_{CC}/2$ ,  $T_{amb} = 25^{\circ}\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified) (continued)**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
THD	Total harmonic distortion	$V_{out} = 2\text{ V}_{p-p}$ , $f = 1\text{ kHz}$ , $A_v = 1$ , $R_L = 600\ \Omega$		0.005		%
$C_s$	Channel separation			120		dB

Figure 3. Output short circuit current vs. output voltage

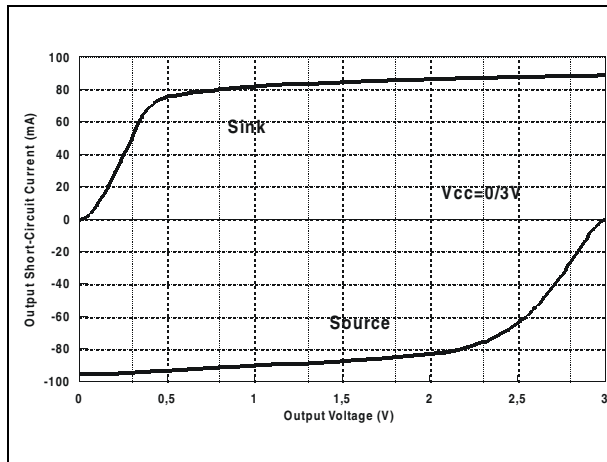


Figure 4. Total supply current vs. supply voltage

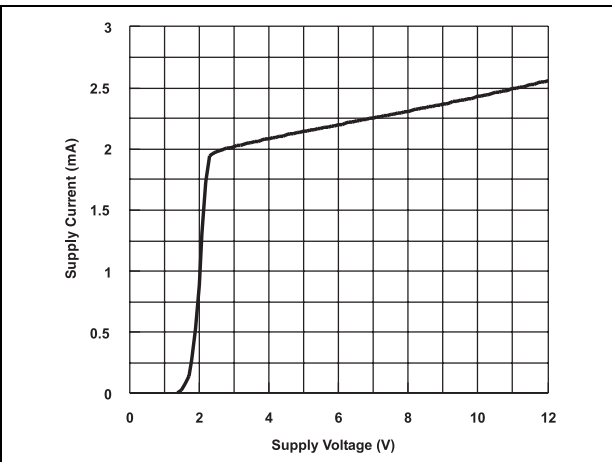


Figure 5. Voltage gain and phase vs. frequency

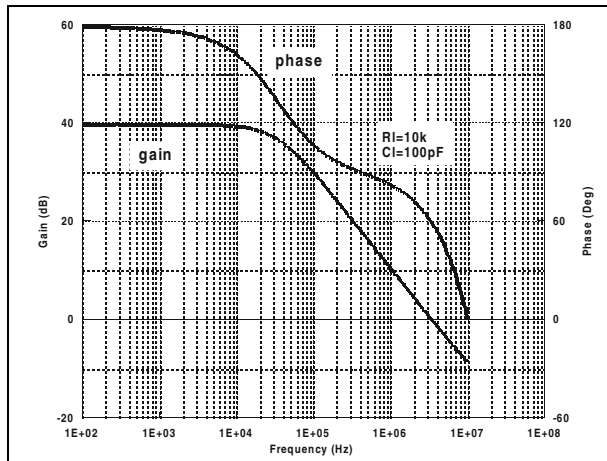


Figure 6. Equivalent input noise voltage vs. frequency

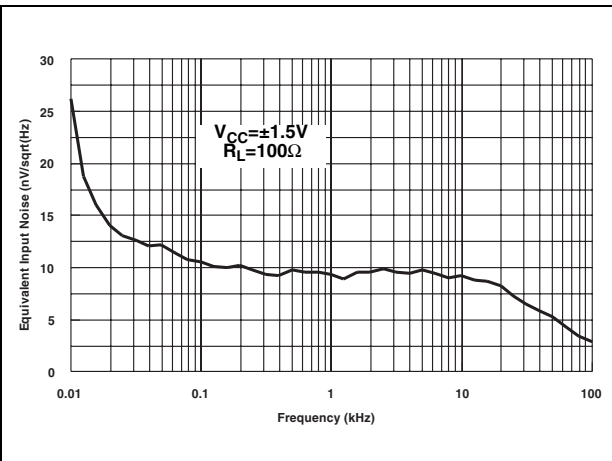


Figure 7. THD + noise vs. frequency

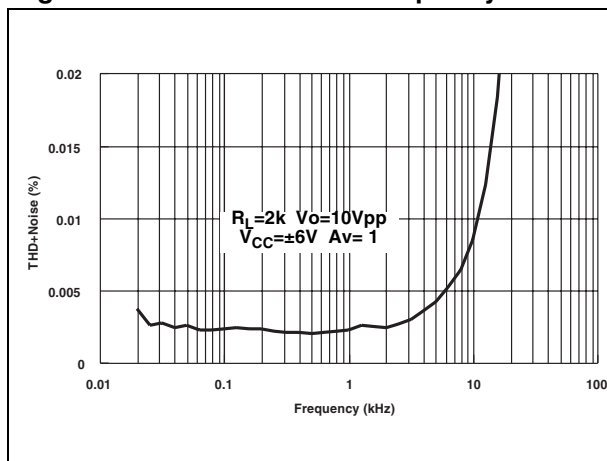


Figure 8. THD + noise vs. frequency

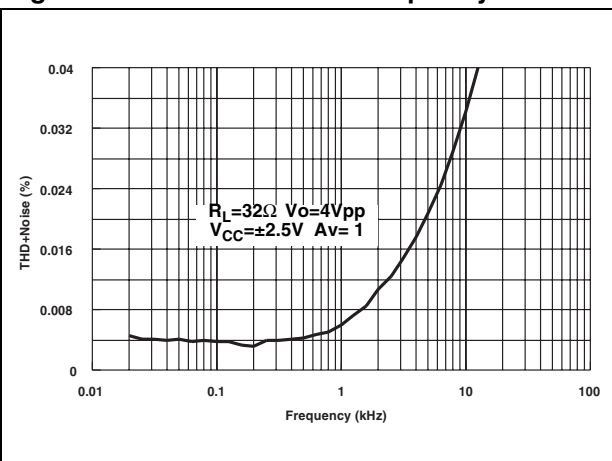


Figure 9. THD + noise vs. frequency

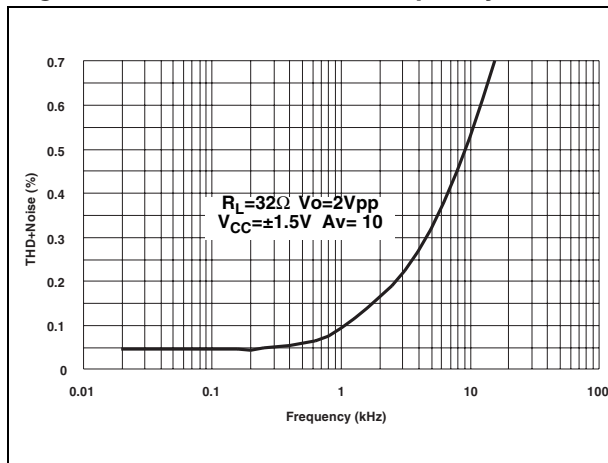


Figure 10. THD + noise vs. output voltage

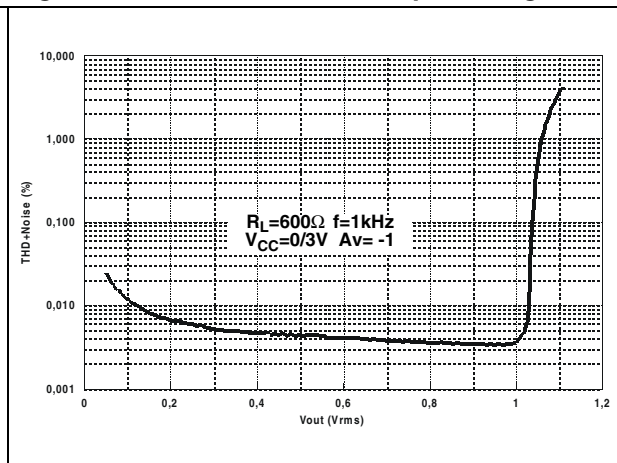


Figure 11. THD + noise vs. output voltage

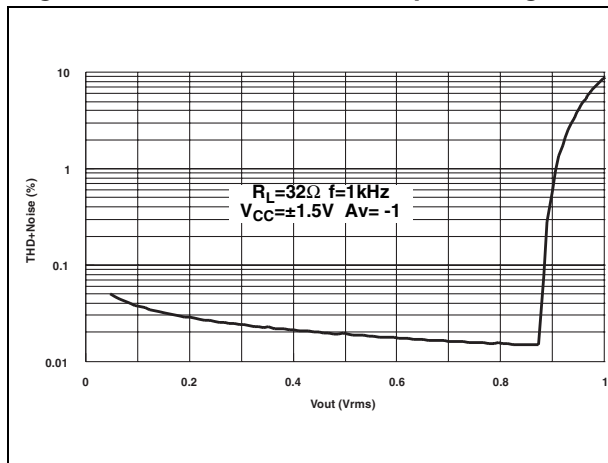


Figure 12. THD + noise vs. output voltage

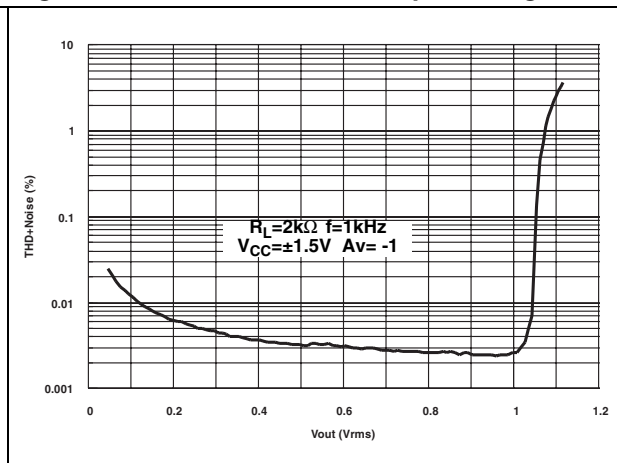
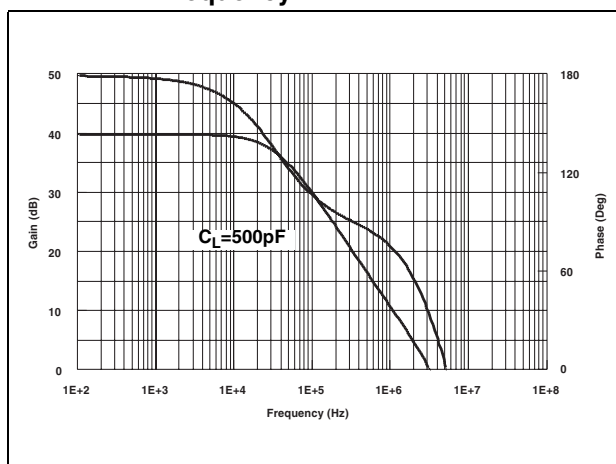


Figure 13. Open loop gain and phase vs. frequency



## 4 Macromodel

### 4.1 Important note concerning this macromodel

- All models are a trade-off between accuracy and complexity (i.e. simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the **nominal** performance of a **typical** device within **specified operating conditions** (temperature, supply voltage, for example). Thus the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions ( $V_{CC}$ , temperature, for example) or even worse, outside of the device operating conditions ( $V_{CC}$ ,  $V_{icm}$ , for example), is not reliable in any way.

[Section 4.2](#) provides the electrical characteristics resulting from the use of this macromodel.

### 4.2 Electrical characteristics from macromodelization

**Table 5. Electrical characteristics resulting from macromodel simulation at  $V_{CC} = 3\text{ V}$ ,  $V_{DD} = 0\text{ V}$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ\text{C}$  (unless otherwise specified)**

Symbol	Conditions	Value	Unit
$V_{io}$		0	mV
$A_{vd}$	$R_L = 10\text{ k}\Omega$	200	V/mV
$I_{CC}$	No load, per operator	1.2	mA
$V_{icm}$		-0.2 to 3.2	V
$V_{OH}$	$R_L = 10\text{ k}\Omega$	2.95	V
$V_{OL}$	$R_L = 10\text{ k}\Omega$	25	mV
$I_{sink}$	$V_O = 3\text{ V}$	80	mA
$I_{source}$	$V_O = 0\text{ V}$	80	mA
GBP	$R_L = 600\text{ k}\Omega$	4	MHz
SR	$R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$	1.3	V/ $\mu\text{s}$
$\phi_m$	$R_L = 600\text{ k}\Omega$	68	Degrees

### 4.3 Macromodel code

```

** Standard Linear Ics Macromodels, 1996.
** CONNECTIONS:
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY
*
.SUBCKT TS92X 1 2 3 4 5
*
.MODEL MDTH D IS=1E-8 KF=2.664234E-16 CJO=10F
*
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 8.125000E+00
RIN 15 16 8.125000E+00
RIS 11 15 2.238465E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 153.5u
VOFN 13 14 DC 0
IPOL 13 5 3.200000E-05
CPS 11 15 1e-9
DINN 17 13 MDTH 400E-12
VIN 17 5 -0.100000e+00
DINR 15 18 MDTH 400E-12
VIP 4 18 0.400000E+00
FCP 4 5 VOFP 1.865000E+02
FCN 5 4 VOFN 1.865000E+02
FIBP 2 5 VOFP 6.250000E-03
FIBN 5 1 VOFN 6.250000E-03
* GM1 STAGE *****
FGM1P 119 5 VOFP 1.1
FGM1N 119 5 VOFN 1.1
RAP 119 4 2.6E+06
RAN 119 5 2.6E+06
* GM2 STAGE *****
G2P 19 5 119 5 1.92E-02
G2N 19 5 119 4 1.92E-02
R2P 19 4 1E+07
R2N 19 5 1E+07
*****
VINT1 500 0 5
GCONVP 500 501 119 4 19.38
VP 501 0 0
GCONVN 500 502 119 5 19.38
VN 502 0 0

```

```
***** orientation isink isource *****
VINT2 503 0 5
FCOPY 503 504 VOUT 1
DCOPYP 504 505 MDTH 400E-9
VCOPYP 505 0 0
DCOPYN 506 504 MDTH 400E-9
VCOPYN 0 506 0
*****
F2PP 19 5 poly(2) VCOYP VP 0 0 0 0 0.5
F2PN 19 5 poly(2) VCOYP VN 0 0 0 0 0.5
F2NP 19 5 poly(2) VCOYN VP 0 0 0 0 1.75
F2NN 19 5 poly(2) VCOYN VN 0 0 0 0 1.75
* COMPENSATION *****
CC 19 119 25p
* OUTPUT *****
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 6.250000E+02
VIPM 28 4 5.000000E+01
HONM 21 27 VOUT 6.250000E+02
VINM 5 27 5.000000E+01
VOUT 3 23 0
ROUT 23 19 6
COUT 3 5 1.300000E-10
DOP 19 25 MDTH 400E-12
VOP 4 25 1.052
DON 24 19 MDTH 400E-12
VON 24 5 1.052
.ENDS;TS92X
```

## 5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 5.1 Flip-chip package (8 bumps)

Figure 14. Top view and dimensions of 8-bump flip-chip

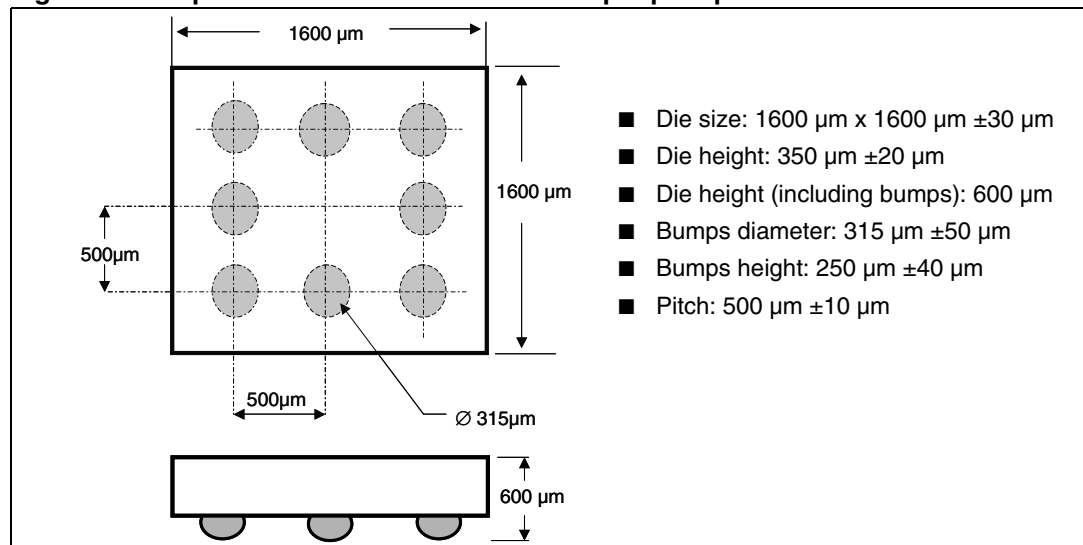


Figure 15. Flip-chip footprint recommendation

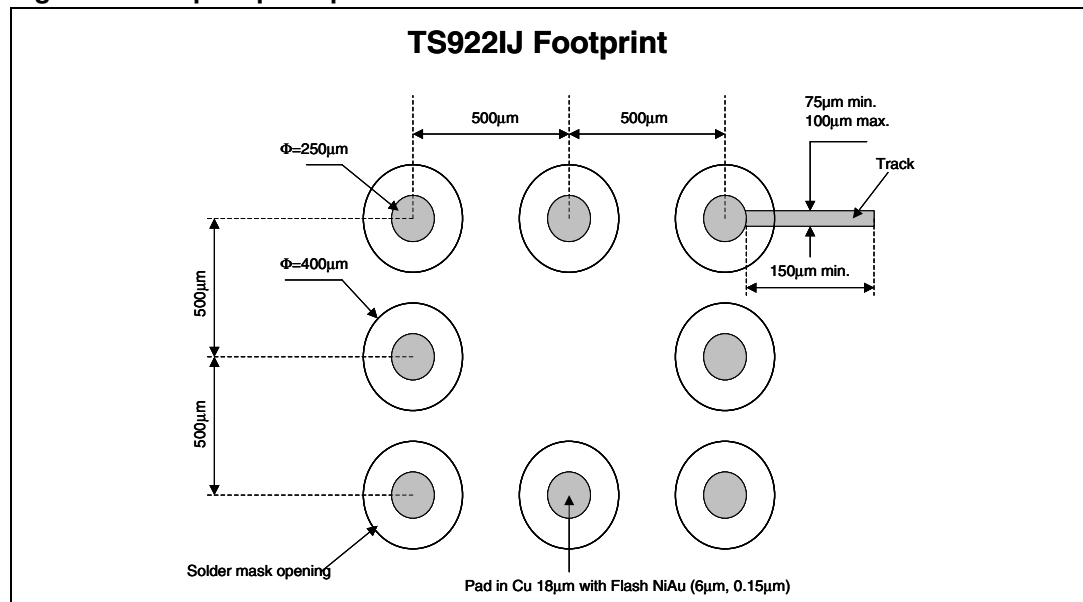


Figure 16. Flip-chip marking (top view)

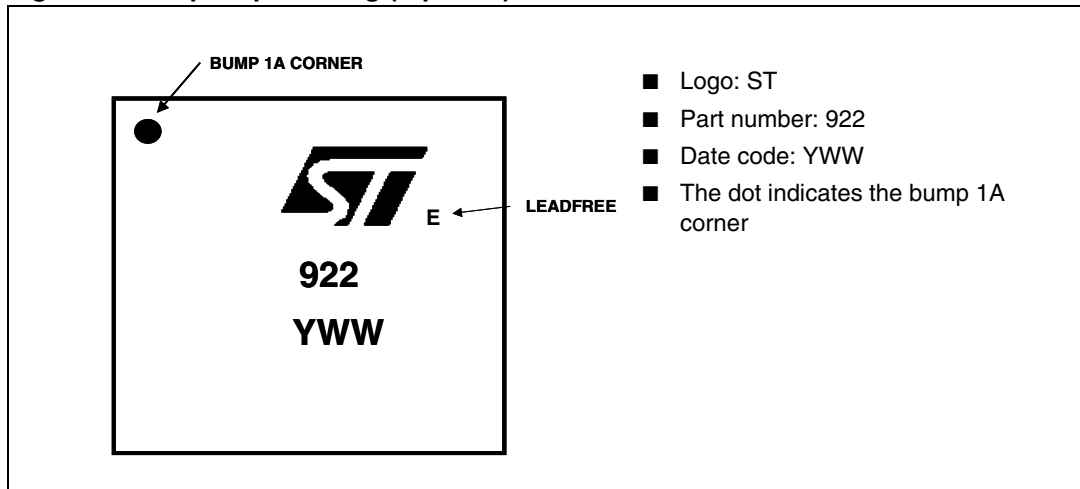
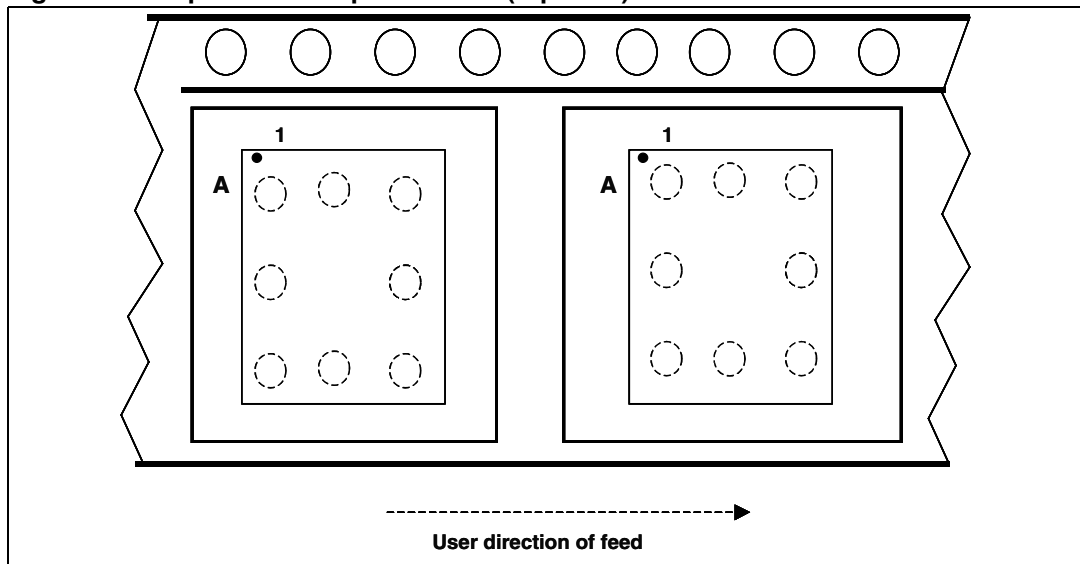


Figure 17. Tape and reel specification (top view)



**Note:** **Device orientation:** the devices are oriented in the carrier pocket with bump number A1 adjacent to the sprocket holes.

## 5.2 SO-8 package

Figure 18. SO-8 package mechanical drawing

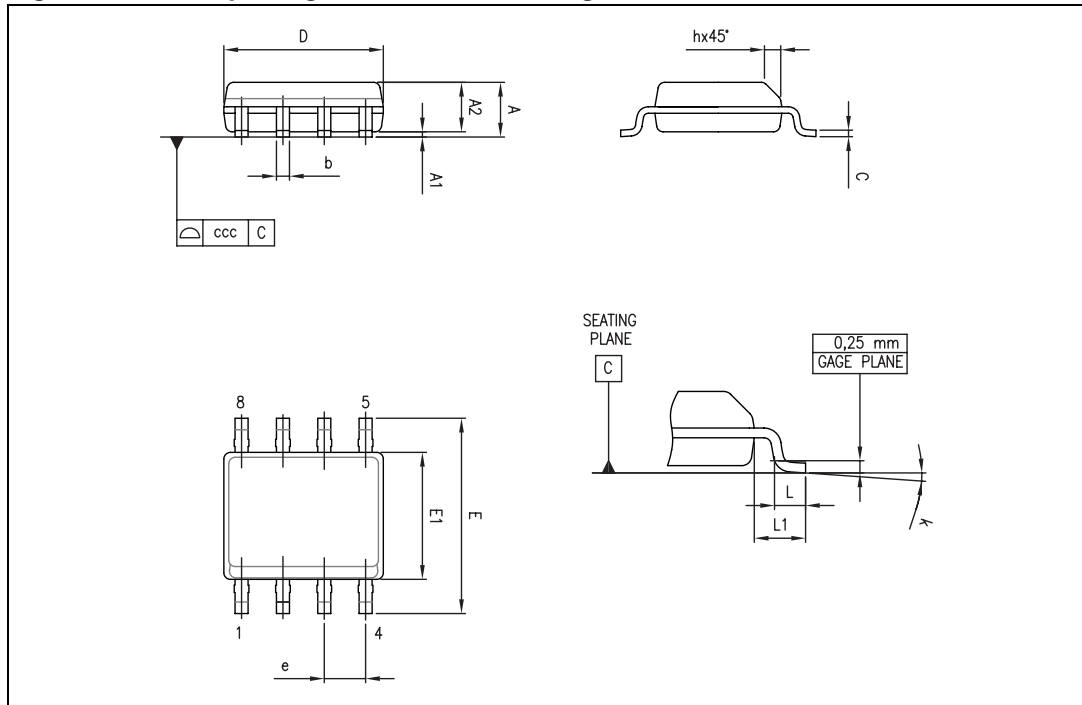


Table 6. SO-8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	0		8°	1°		8°
ccc			0.10			0.004

### 5.3 TSSOP8 package

Figure 19. TSSOP8 package mechanical drawing

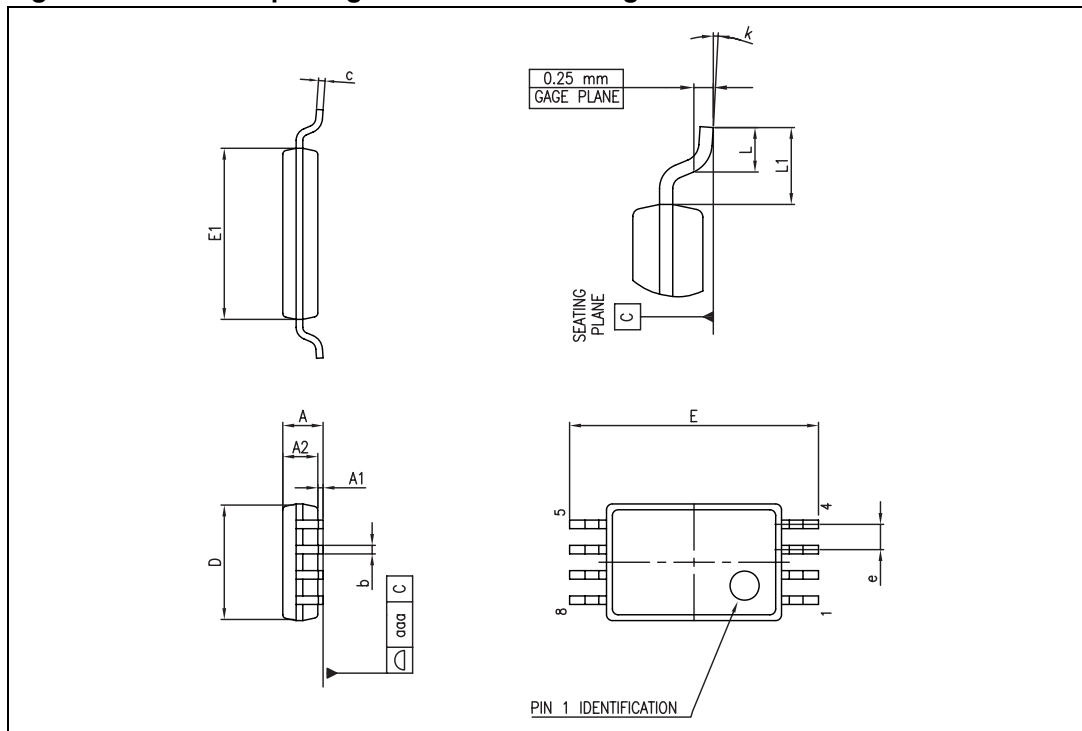


Table 7. TSSOP8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.20			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa			0.10			0.004

## 5.4 DIP8 package

Figure 20. DIP8 package mechanical drawing

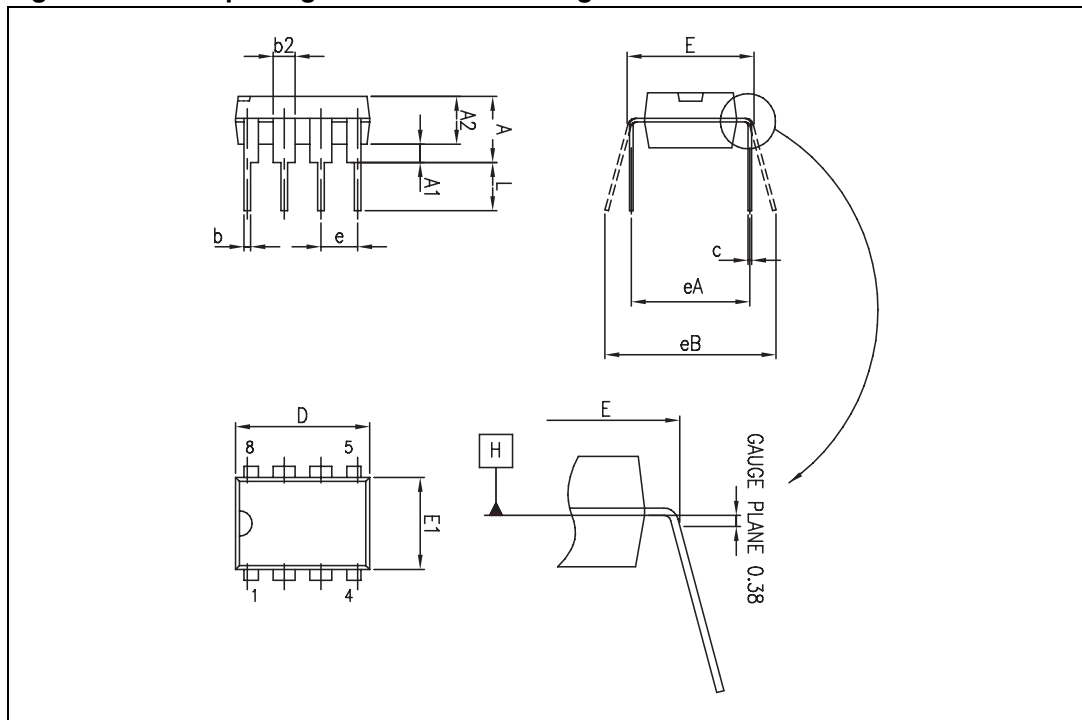


Table 8. DIP8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
c	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
e		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

## 6 Ordering information

**Table 9. Order codes**

Part number	Temperature range	Package	Packaging	Marking
TS922ID TS922IDT	-40°C, +125°C	SO-8	Tube or Tape & reel	922I
TS922AID TS922AIDT				922AI
TS922IYD <sup>(1)</sup> TS922IYDT <sup>(1)</sup>		SO-8 (Automotive grade)	Tube or Tape & reel	922IY
TS922AIYDT <sup>(1)</sup>			Tape & reel	922AIY
TS922IPT		TSSOP8	Tape & reel	922I
TS922AIPT				922AI
TS922IN		DIP8	Tube	TS922IN
TS922IYPT <sup>(2)</sup> TS922AIYPT <sup>(2)</sup>		TSSOP8 (Automotive grade)	Tape & reel	922IY
				922AY
TS922IJT/EIJT		Flip-chip	Tape & reel	922

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

2. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent are ongoing.

## 7 Revision history

**Table 10. Document revision history**

Date	Revision	Changes
01-Feb-2001	1	First release.
01-Jul-2004	2	Flip-chip package inserted in the document.
02-May-2005	3	Modifications in AMR <a href="#">Table 1 on page 3</a> (explanation of $V_{id}$ and $V_i$ limits, ESD MM and CDM values added, $R_{thja}$ added).
01-Aug-2005	4	PPAP references inserted in the datasheet, see <a href="#">Table 6 on page 19</a> .
01-Mar-2006	5	TS922EIJT part number inserted in the datasheet, see <a href="#">Table 6 on page 19</a> .
26-Jan-2007	6	Modifications in AMR <a href="#">Table 1 on page 3</a> ( $R_{thjc}$ added), parameter limits on full temperature range added in <a href="#">Table 3 on page 5</a> and <a href="#">Table 4 on page 7</a> .
12-Nov-2007	7	Added notes on ESD in AMR table. Re-formatted package information. Added notes for automotive grade in order codes table.
02-Feb-2010	8	Document reformatted. Added root part number TS922A on cover page. Removed TS922AIYD order code from <a href="#">Table 9</a> .

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